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Kind regards,

Team Nexperia



# PRTR5V0U2D

# Ultra low capacitance double rail-to-rail ESD protection Rev. 01 — 28 April 2009 Product date

**Product data sheet** 

#### **Product profile**

#### 1.1 General description

Ultra low capacitance double rail-to-rail ElectroStatic Discharge (ESD) protection device in a SOT457 (SC-74) small Surface-Mounted Device (SMD) plastic package.

The device is designed to protect two Hi-Speed data lines or high-frequency signal lines from the damage caused by ESD and other transients.

PRTR5V0U2D integrates two ultra low capacitance rail-to-rail ESD protection channels and one additional ESD protection diode to ensure signal line protection even if no supply voltage is available.

#### 1.2 Features

- ESD protection of two Hi-Speed data lines or high-frequency signal lines
- Ultra low input/output to ground capacitance: C<sub>(I/O-GND)</sub> = 1 pF
- ESD protection up to 8 kV
- IEC 61000-4-2, level 4 (ESD)
- Very low clamping voltage due to an integrated additional ESD protection diode
- Very low reverse current
- AEC-Q101 qualified (85 °C)
- Small SMD plastic package

#### 1.3 Applications

- USB 2.0 interfaces
- Digital Video Interface (DVI)
- High Definition Multimedia Interface (HDMI)
- Mobile and cordless phones
- Personal Digital Assistants (PDA)
- Digital cameras
- Wide Area Network (WAN) / Local Area Network (LAN) systems
- PCs, notebooks, printers and other PC peripherals



#### 1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per channe	el					
C <sub>(I/O-GND)</sub>	input/output to ground capacitance	f = 1 MHz; $V_{(I/O-GND)} = 0 V$	<u>[1]</u> -	1.0	1.5	pF
C <sub>(I/O-I/O)</sub>	input/output to input/output capacitance	f = 1  MHz; $V_{(I/O-I/O)} = 0 \text{ V}$	[2] _	0.6	-	pF
Zener diod	е					
$V_{RWM}$	reverse standoff voltage		[3]	-	5.5	V
C <sub>sup</sub>	supply pin to ground capacitance	f = 1 MHz; $V_{CC} = 0 V$	[3] _	16	-	pF

<sup>[1]</sup> Measured from pin 1, 3, 4 or 6 to ground.

### 2. Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I/O1	input/output 1	D- D- D.	
2	GND	ground	<u> </u>	1 6
3	I/O2	input/output 2	0	
4	I/O2	input/output 2	<u> </u>	2 5
5	$V_{CC}$	supply voltage		
6	I/O1	input/output 1		3 006aab349

# 3. Ordering information

Table 3. Ordering information

Type number	Package	Package			
	Name	Description	Version		
PRTR5V0U2D	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457		

### 4. Marking

Table 4. Marking codes

Type number	Marking code
PRTR5V0U2D	ZB

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<sup>[2]</sup> Measured from pin 1 or 6 to pin 3 or 4.

<sup>[3]</sup> Measured from pin 5 to ground.



## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
T <sub>amb</sub>	ambient temperature		-40	+85	°C
T <sub>stg</sub>	storage temperature		-55	+125	°C

#### Table 6. ESD maximum ratings

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
Per chann	nel					
$V_{ESD}$	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1][2]	-	8	kV
		MIL-STD-883 (human body model)	[2]	-	10	kV

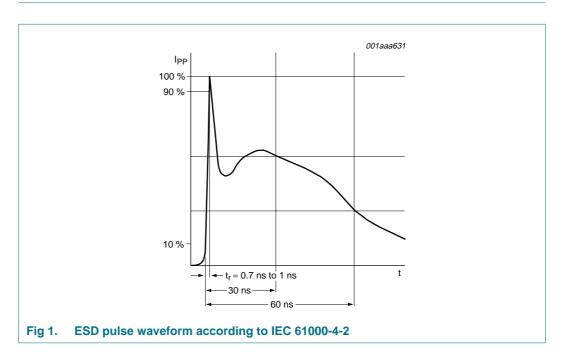
<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

<sup>[2]</sup> Measured from pin 1, 3, 4 or 6 to pin 2 or 5.



Table 7. ESD standards compliance

Standard	Conditions
Per channel	
IEC 61000-4-2; level 4 (ESD)	> 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV



#### 6. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Tarrib = 20 0	and = 20 C arried deciment					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per channel						
I <sub>R</sub>	reverse current	$V_R = 5 V$	<u>[1]</u> _	< 1	100	nA
$C_{\text{(I/O-GND)}}$	input/output to ground capacitance	f = 1 MHz; $V_{(I/O-GND)} = 0 V$	<u>[1]</u> _	1.0	1.5	pF
C <sub>(I/O-I/O)</sub>	input/output to input/output capacitance	f = 1  MHz; $V_{(I/O-I/O)} = 0 \text{ V}$	[2] _	0.6	-	pF
$V_{F}$	forward voltage	$I_F = 1 \text{ mA}$	[3] _	0.7	-	V
Zener diode						
$V_{RWM}$	reverse standoff voltage		[4] _	-	5.5	V
$V_{BR}$	breakdown voltage		<u>[4]</u> 6	-	9	V
C <sub>sup</sub>	supply pin to ground capacitance	f = 1 MHz; $V_{CC} = 0 V$	<u>[4]</u> _	16	-	pF

- [1] Measured from pin 1, 3, 4 or 6 to ground.
- [2] Measured from pin 1 or 6 to pin 3 or 4.
- [3] Measured from pin 1, 3, 4 or 6 to pin 5.
- [4] Measured from pin 5 to ground.

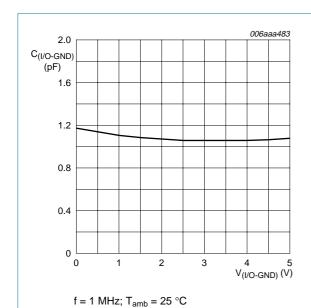


Fig 2. Input/output to ground capacitance as a function of input/output to ground voltage; typical values

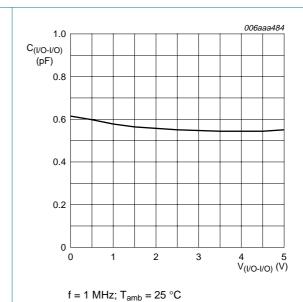
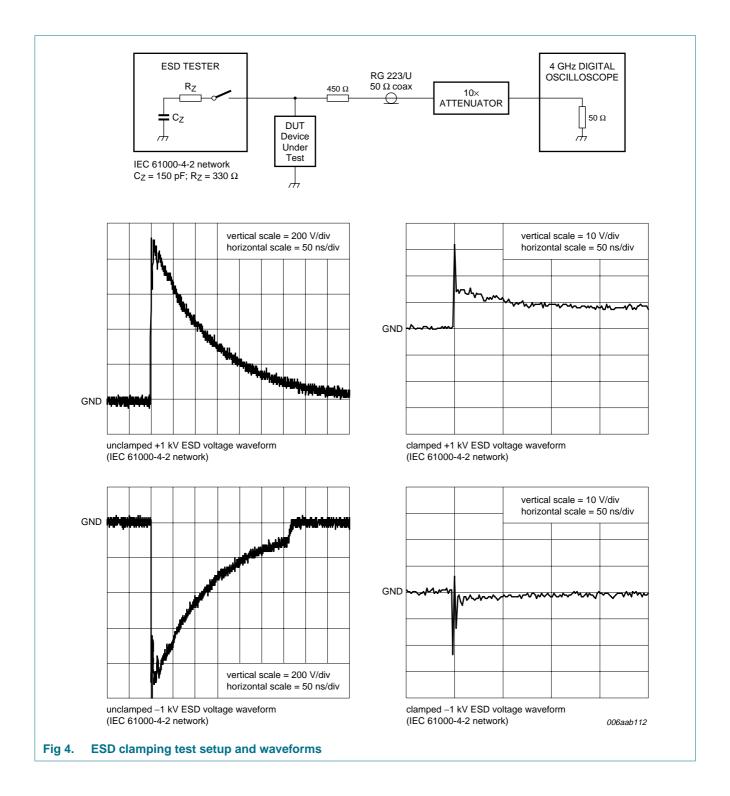


Fig 3. Input/output to ground capacitance as a function of input/output to input/output voltage; typical values

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# PRTR5V0U2D

#### Ultra low capacitance double rail-to-rail ESD protection



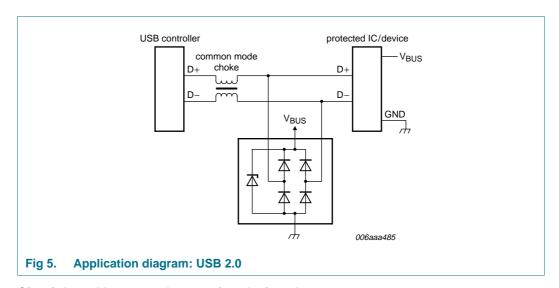
### 7. Application information

Handling data rates up to 480 Mbit/s, USB 2.0 interfaces require ESD protection devices with an extremely low line capacitance in order to avoid signal distortion.

With a capacitance of only 1 pF, the PRTR5V0U2D offers IEC 61000-4-2, level 4 compliant ESD protection.

The PRTR5V0U2D integrates two ultra low capacitance rail-to-rail ESD protection channels and one additional ESD protection diode.

The additional ESD protection diode connected between ground and  $V_{CC}$  prevents charging of the supply.

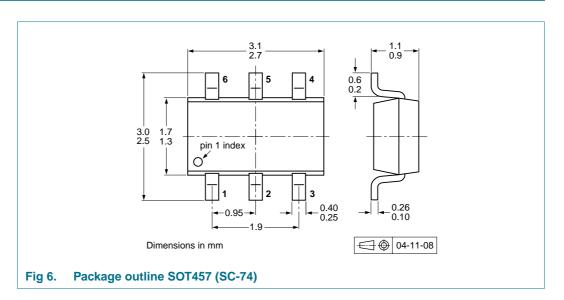


#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PRTR5V0U2D as close to the input terminal or connector as possible.
- The path length between the PRTR5V0U2D and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

### 8. Package outline



## 9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description		Packing q	uantity
				3000	10000
PRTR5V0U2D	SOT457	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

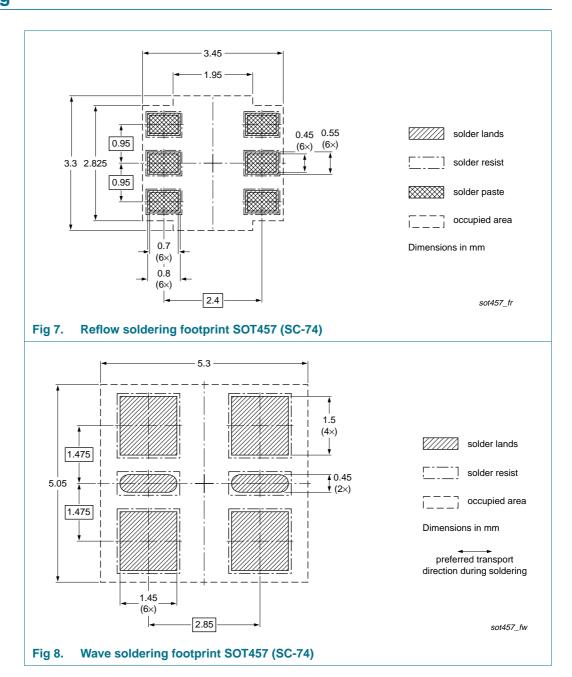
[1] For further information and the availability of packing methods, see  $\underline{\text{Section } 13}$ .

[2] T1: normal taping

[3] T2: reverse taping



### 10. Soldering





## 11. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PRTR5V0U2D_1	20090428	Product data sheet	-	-



### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# PRTR5V0U2D

#### Ultra low capacitance double rail-to-rail ESD protection

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